

A177 Single Output Hall Effect Latch IC

Description

The A177 is an integrated Hall effect latched sensor with output pull-high resistor driver designed for electronic commutation of brushless DC motor applications and contactless switches. The device includes an on-chip Hall voltage generator for magnetic sensing, a comparator that amplifies the Hall voltage, and a Schmitt trigger to provide switching hysteresis for noise rejection, and output driver with pull-high resistor. An internal bandgap regulator is used to provide temperature compensated supply voltage for internal circuits and allows a wide operating supply range.

If a magnetic flux density larger than threshold B_{op} , DO is turned on (low). The output state is held until a magnetic flux density reversal falls below B_{rp} causing DO to be turned off (high).

A177 is rated for operation over temperature range from -40°C to 150°C and voltage range from 3.5V to 28V. The devices are available in low cost die forms or rugged 3 pin SIP packages.

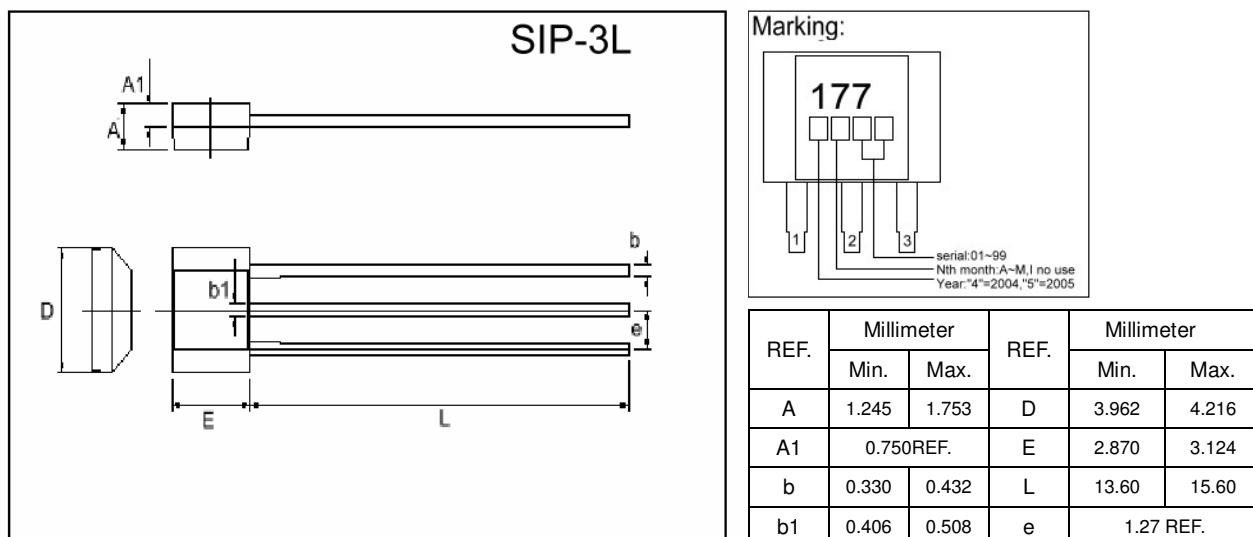
Features

- * Wide range of supply voltage: 3.5V to 28V.
- * Internal bandgap regulator allows temperature compensated operations and a wide operating voltage range.
- * High sensitivity with a small magnet.
- * TTL and MOS ICs directly drivable by output.
- * Build in protection diode for chip reverse power connecting.

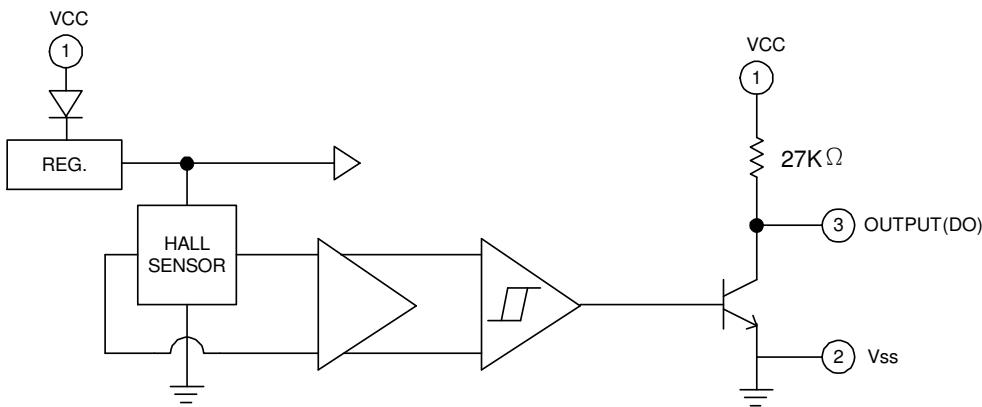
Application

- | | |
|---------------------|------------------------|
| 1) Brushless DC Fan | 5) Revolution Counting |
| 2) Brushless DC Fan | 6) Speed Measurement |
| 3) Position Sensors | 7) Keyboard Switches |
| 4) Rotation Sensors | 8) Microswitches |

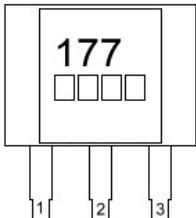
Package Dimensions



Functional Block Diagrams



Pin Descriptions



Name	P/I/O	Pin#	Description
Vcc	P	1	Positive power supply
Vss	P	2	Ground
DO	O	3	Digital output

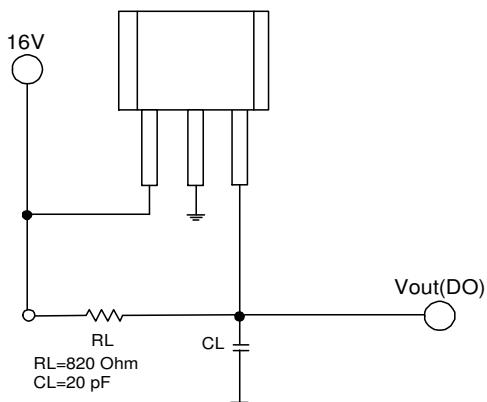
Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Value	Unit
Supply Voltage	Vcc	28V	V
Reverse Vcc Polarity Voltage	VRCC	-28V	V
Magnetic flux density	B	Unlimited	
Output OFF Voltage	Vce	35	V
Output ON Current	Ic Continuous	25	mA
Operating Temperature Range	Ta	-40~150	°C
Storage Temperature Range	Ts	-65~150	°C
Package Power Dissipation	PD	250	mW
Maximum Junction Temp.	Tj	175	°C

Electrical Characteristics (TA=+25°C)

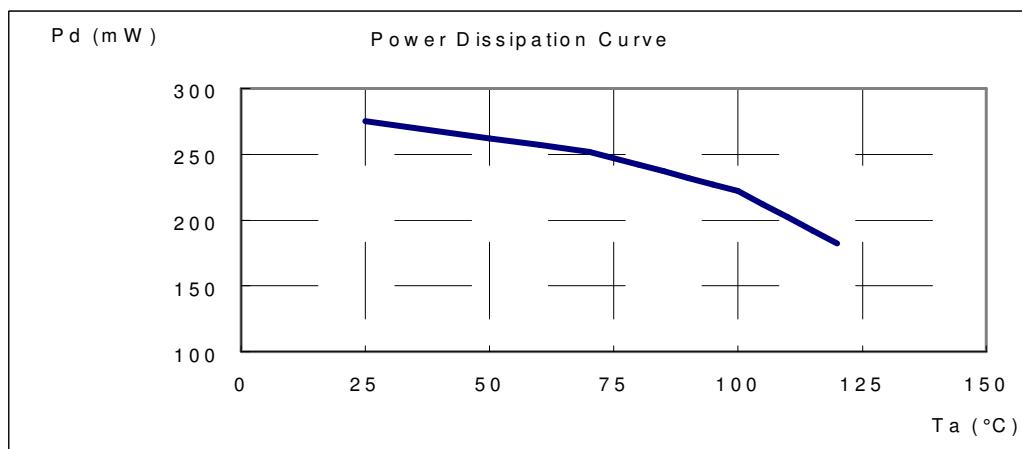
Parameter	Symbol	Test Conditions	Min	Typ.	Max.	Unit
Supply Voltage	Vcc	-	3.5	-	28	V
Low output voltage	VOL	Vcc=16V, Io=12mA, B=130 Gauss	-	-	0.4	V
		Vcc=3.6V, Io=12mA, B=130 Gauss	-	-	0.4	V
High output voltage	VOH	Vcc=16V, Io=-30µA, B=-130 Gauss	14.6	-	-	V
		Vcc=3.6V, Io=-30µA, B=-130 Gauss	2.2	-	-	V
Output Leakage Current	Icex	Vcc=16V, Vcc=16V	-	<0.1	10	uA
Output Short-circuit Current	-Ios	Vcc=16V, Vo=0V, B=-130 Gauss	0.4	-	0.9	mA
Supply Current	Icc	Vcc=24V, Output Open	-	5	10	mA
Output Rise Time	tr	Vcc=16V, RL=820Ω CL=20pf	-	0.3	1.5	us
Output Falling Time	tf	Vcc=16V, RL=820Ω CL=20pf	-	0.3	1.5	us

Test Circuit

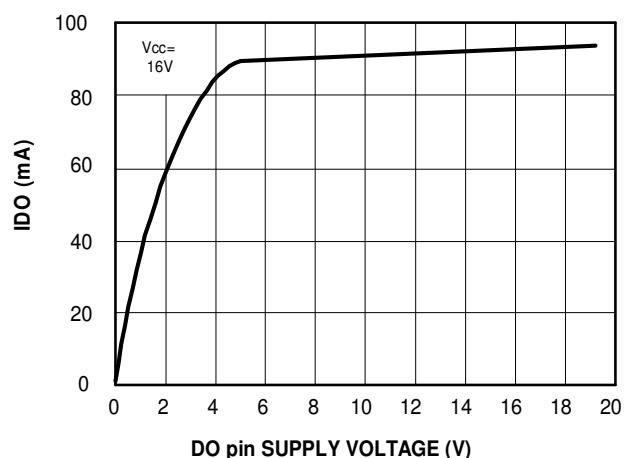


Power dissipation VS. Environment Temperature

T _a (°C)	25	50	60	70	80	85	90	95	100	105	110	115	120
P _d (mW)	275	262	257	252	242	237	232	227	222	212	202	192	182



Electrical Characteristics Curves

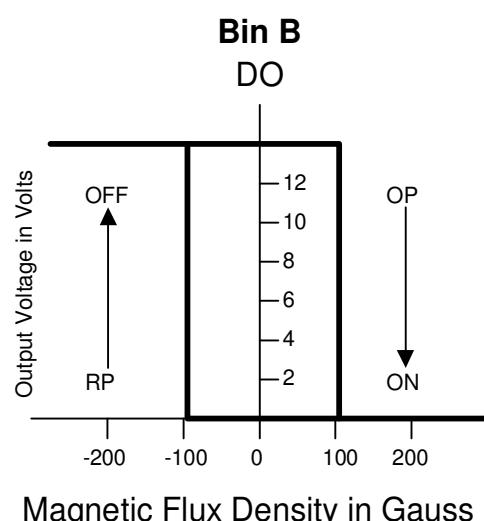
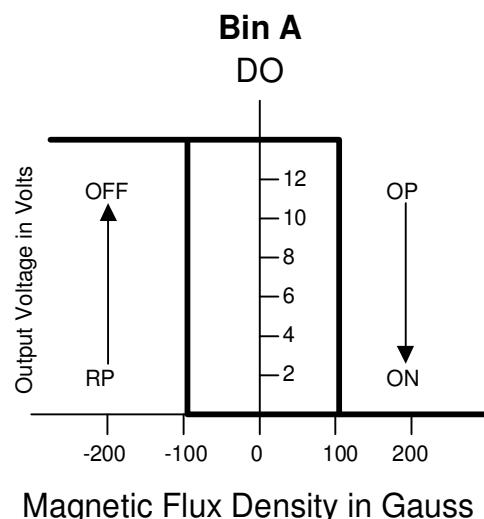


Current capacity vs. supply voltage for DO pin

Magnetic Characteristics

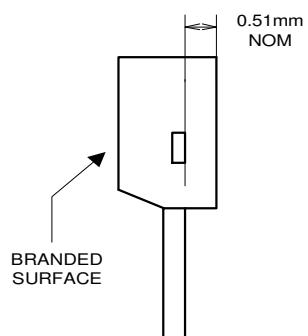
Characteristic		Symbol	Ta=+25°C		Ta=-40°C to 150°C		Unit
			Min	Max	Min	Max	
Operate Point	BIN A	Bop	5	100	5	100	Gauss
	BIN B	Bop	-20	100	-20	100	Gauss
Release Point	BIN A	Brp	-5	-100	-5	-100	Gauss
	BIN B	Brp	20	-100	20	-100	Gauss
Hysteresis	BIN A	Bphys	75	100	55	120	Gauss
	BIN B	Bphys	70	110	50	130	Gauss

Hysteresis Characteristics



Package Information

Active Area Depth



Package Sensor Location

